



Features:

- RoHS Compliant
- 150 Watts
- DC 3.0 GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Chip Termination 150 Watts, 50Ω

Description

The A150N50X4E is high performance Aluminum Nitride (AIN) chip termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators and for use in power combiners. The termination is also RoHS compliant!

General Specifications

Resistive Element Thick film
Substrate AIN Ceramic

Terminal Finish Matte Tin over Nickel Barrier

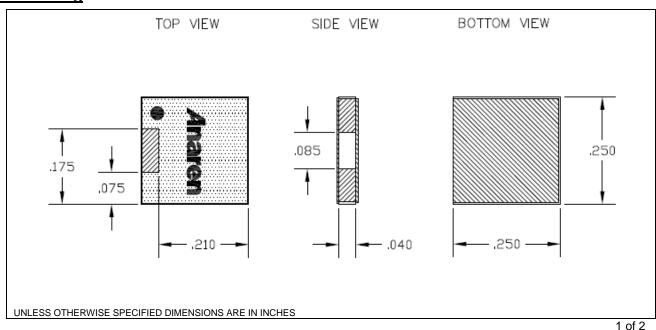
Operating Temperature -50 to +200°C (see de rating chart)

Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. All dimensions in inches.

Electrical Specifications

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

Outline Drawing

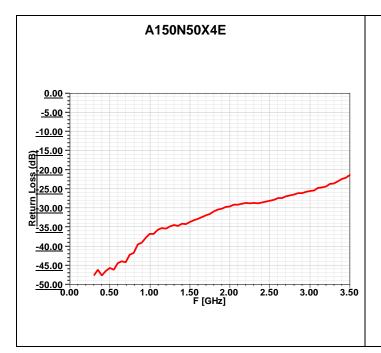


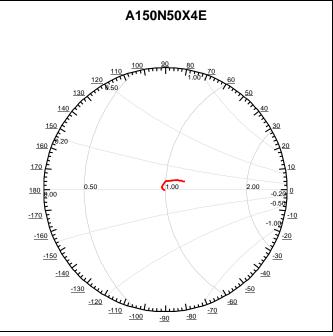


USA/Canada: (315) 432-8909 Toll Free: (800) 544-2414 Europe: +44 2392-232392



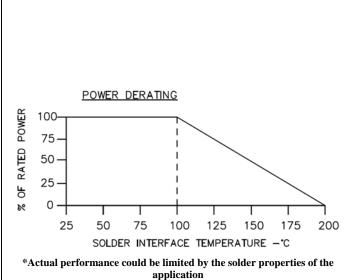
Typical Performance:

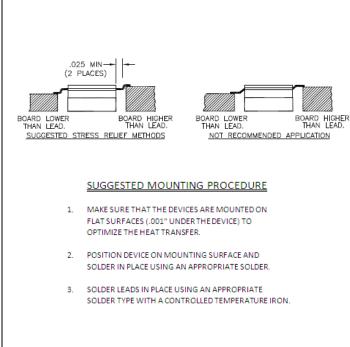




Power De-rating:

Mounting Footprint and Procedure:





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Anaren:

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